

Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company

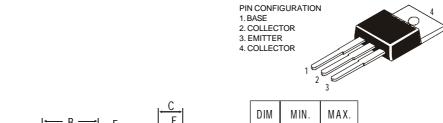


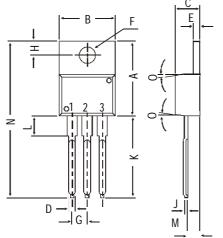
TO-220 Plastic Package

2N6109

2N6109 PNP PLASTIC POWER TRANSISTOR

General Purpose Amplifier and Switching Application





diminsions in mm.	DIM	MIN.	MAX.	
	Α	14.42	16.51	
	В	9.63	10.67	
	С	3.56	4.83	
	D		0.90	
	E	1.15	1.40	
	F	3.75	3.88	
	G	2.29	2.79	
	Н	2.54	3.43	
	J		0.56	
	K	12.70	14.73	
	L	2.80	4.07	
	M	2.03	2.92	
	N		31.24	
₹	0	DEG 7		

ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	V_{CBO}	max.	60 V
Collector-emitter voltage (open base)	$V_{C\!E\!O}$	max.	50 V
Collector current	I_C	max.	7.0 A
Total power dissipation up to $T_C = 25^{\circ}C$	P_{tot}	max.	40 W
Junction temperature	T_{j}	max.	150 °C
Collector-emitter saturation voltage	•		
$I_C = 2.5A$; $I_B = 0.25A$	V_{CEsat}	max.	1.0 V
D.C. current gain			
$I_C = 2.5A; \ V_{CE} = 4V$	$h_{\!F\!E}$	min.	<i>30</i>
		max.	<i>150</i>

RATINGS (at T_A =25°C unless otherwise specified) Limiting values

V_{CBO}	max.	60 V
$V_{C\!E\!O}$	max.	50 V
V_{EBO}	max.	5.0 V
I_C	max.	7.0 A
	V _{CEO} V _{EBO}	VCEO max. VEBO max.

Collector current (Peak value)	I_C	max.	10 A	
Base current	I_B	max.	3.0 A	
Total power dissipation up to $T_C = 25^{\circ}C$	P_{tot}	max.	40 W	
Derate above 25°C		max.	0.32 W/°C	
Junction temperature	T_{j}	max.	150 °C	
Storage temperature	\check{T}_{stg}	−65 to	-65 to +150 ℃	
THERMAL CHARACTERISTICS				
From junction to case	R_{thj-c}		3.125 °C/W	
CHARACTERISTICS				
$T_{amb} = 25^{\circ}C$ unless otherwise specified				
Collector cutoff current				
$I_B = 0$; $V_{CE} = 40V$	I_{CEO}	max.	1.0 mA	
$V_{EB(off)} = 1.5V; V_{CE} = 60V$	I_{CEX}	max.	0.1 mA	
$V_{EB(off)} = 1.5V; V_{CE} = 50V; T_C = 150^{\circ}C$	I_{CEX}	max.	2.0 mA	
Emitter cut-off current	_			
$I_C = 0; V_{EB} = 5V$	I_{EBO}	max.	1.0 mA	
Breakdown voltages				
$I_C = 100 \text{ mA}; I_B = 0$	$V_{CEO(sus)}^*$	min.	50 V	
$I_C = 1 \text{ mA}; I_E = 0$	V_{CBO}	min.	60 V	
IE = 1 mA; IC = 0	V_{EBO}	min.	5.0 V	
Saturation voltages				
$I_C = 2.5 A; I_B = 0.25 A$	V_{CEsat}^*	max.	1.0 V	
$I_C = 7 A$; $I_B = 3 A$	V_{CEsat}^*	max.	3.5 V	
Base emitter on voltages				
$I_C = 2.5A$; $V_{CE} = 4V$	$V_{BE(on)}^*$	max.	1.5 V	
$I_C = 7A$; $V_{CE} = 4V$	$V_{BE(on)}^*$	max.	3.0 V	
D.C. current gain				
$I_C = 2.5A$; $V_{CE} = 4V$	$h_{\!F\!E}^*$	min.	30	
		max.	150	
$I_C = 7A$; $V_{CE} = 4V$	$h_{\!F\!E}^*$	min.	2.3	
Small-signal current gain $f = 50$ KHz				
$I_C = 0.5A$; $V_{CE} = 4V$	h_{fe}	min.	20	
Output capacitance at $f = 1$ MHz				
$I_E = 0$; $V_{CB} = 10V$	C_{o}	max.	250 pF	
Transition frequency at $f = 1$ MHz	Ü		1	
$I_C = 500 \text{ mA}; V_{CE} = 4V$	f_T (1)	min.	10 MHz	
	* * /			

^{*} Pulse test: pulse width \leq 300 µs; duty cycle \leq 2%. (1) $f_T = /h_{\rm fe}/\bullet f_{\rm test}$

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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